



SMALL SIGNAL SWITCHING DIODES

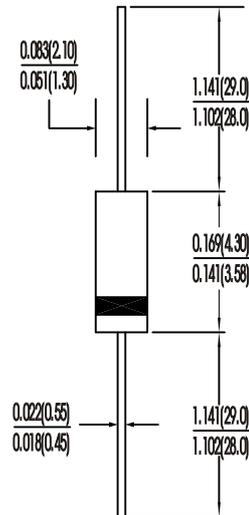
Features

High reliability

Applications

For general purpose

DO-35 (GLASS)



Absolute Maximum Ratings

Dimensions in inches and (millimeters)

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Repetitive peak reverse voltage		BAV19	$V_{RRM}$	120	V
		BAV20	$V_{RRM}$	200	V
		BAV21	$V_{RRM}$	250	V
Reverse voltage		BAV19	$V_R$	100	V
		BAV20	$V_R$	150	V
		BAV21	$V_R$	200	V
Peak forward surge current	$t < 1\text{s}, T_j = 25^\circ\text{C}$		$I_{FSM}$	1	A
Repetitive peak forward current			$I_{FRM}$	625	mA
Forward DC current	$T_{amb} = 25^\circ\text{C}$		$I_F$	250	mA
Rectified current (Average)			$I_{FAV}$	200	mA
Power dissipation	$T_{amb} \leq 25^\circ\text{C}$		$P_{tot}$	500	mW
Junction temperature			$T_j$	175	$^\circ\text{C}$
Storage temperature range			$T_{stg}$	-65~+175	$^\circ\text{C}$

Maximum Thermal Resistance

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	$l = 4\text{mm}, T_L = \text{constant}$	$R_{th,JA}$	350	K/W

Stresses exceeding maximum ratings may damage the device. Maximum ratings are stress ratings only. Functional operation above the recommended operating conditions is not implied. Extended exposure to stresses above the recommended operating conditions may affect device reliability.



RATINGS AND CHARACTERISTIC CURVES

Electrical Characteristics

$T_j=25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F=100\text{mA}$		$V_F$			1.00	V
Reverse current	$V_R=100\text{V}$	BAV19	$I_R$			100	nA
	$V_R=100\text{V}, T_j=100^\circ\text{C}$	BAV19	$I_R$			15	$\mu\text{A}$
	$V_R=150\text{V}$	BAV20	$I_R$			100	nA
	$V_R=150\text{V}, T_j=100^\circ\text{C}$	BAV20	$I_R$			15	$\mu\text{A}$
	$V_R=200\text{V}$	BAV21	$I_R$			100	nA
	$V_R=200\text{V}, T_j=100^\circ\text{C}$	BAV21	$I_R$			15	$\mu\text{A}$
Dynamic forward resistance	$I_F=10\text{mA}$		$r_f$		5		$\Omega$
Diode capacitance	$V_R=0, f=1\text{MHz}$		$C_D$			4	pF
Reverse recovery time	$I_F=I_R=30\text{mA}, I_{rr}=3\text{mA}, R_L=100\Omega$		$t_{rr}$			50	ns

Characteristics ( $T_j=25^\circ\text{C}$  unless otherwise specified)

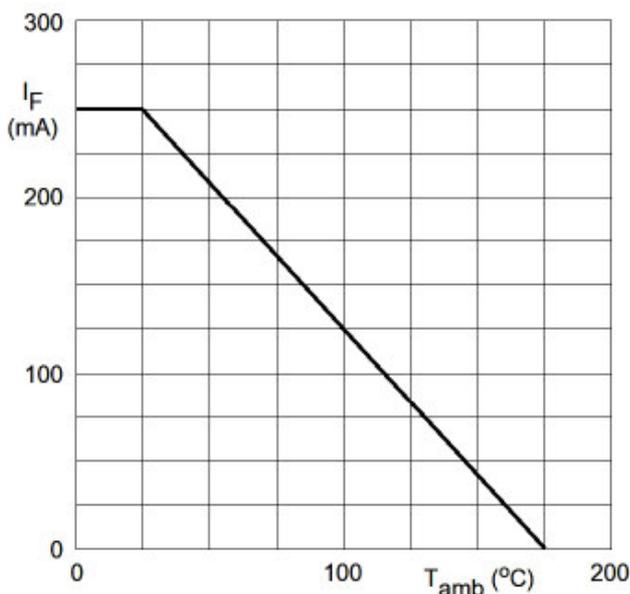


Figure 1. Maximum permissible continuous forward current vs. ambient temperature

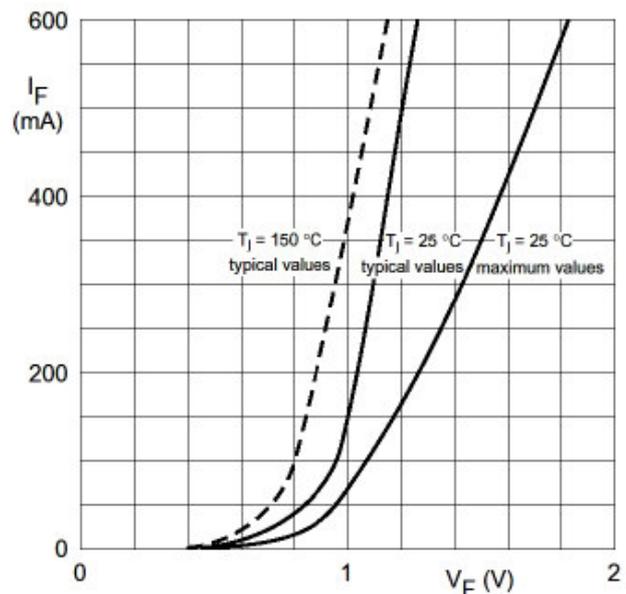


Figure 2. Forward current vs. forward voltage



RATINGS AND CHARACTERISTIC CURVES

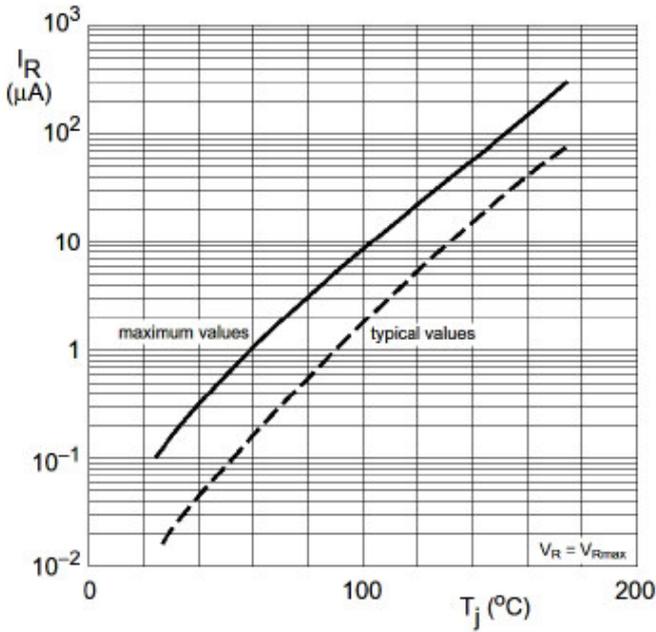


Figure 3. Reverse current vs. junction temperature

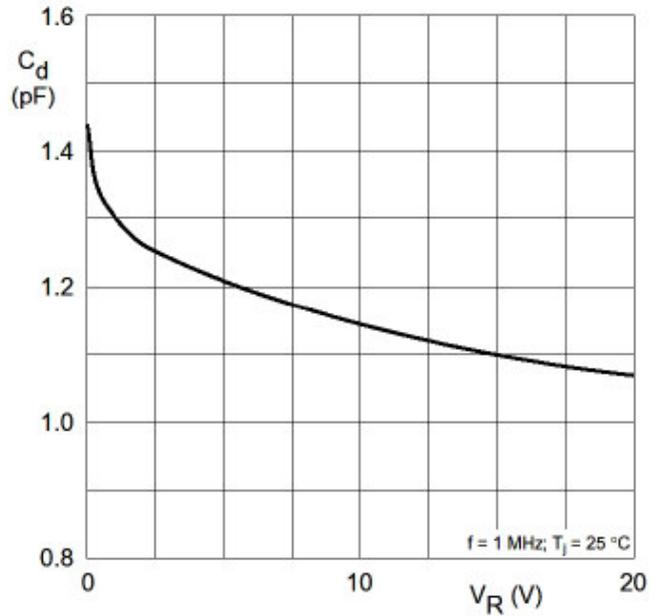


Figure 4. Diode capacitance vs. reverse voltage (Typical values)

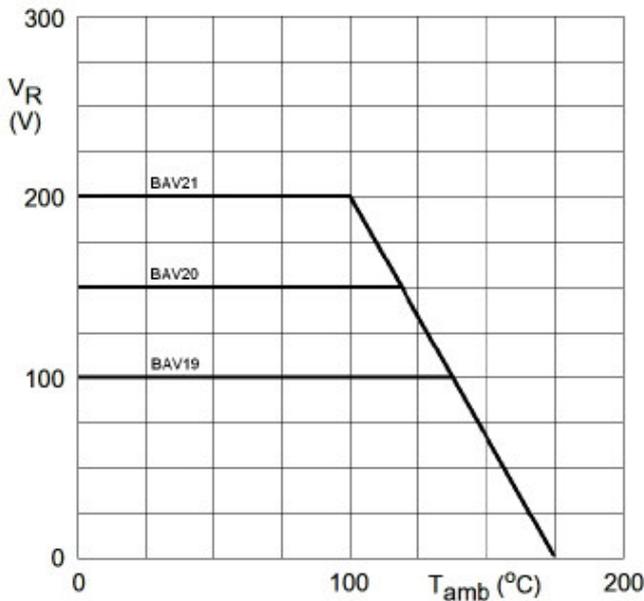


Figure 3. Maximum permissible continuous reverse voltage vs. ambient temperature



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